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Spin-orbit torque magnetization switching of a three-terminal perpendicular magnetic tunnel junction

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#	Paper	IF	Citations
283	Quantitative estimation of the spin-wave features supported by a spin-torque-driven magnetic waveguide. <b>2014</b> , 116, 213908		4
282	Interplay of spin-orbit torque and thermoelectric effects in ferromagnet/normal-metal bilayers. <i>Physical Review B</i> , <b>2014</b> , 90,	3.3	185
281	Macrospin modeling of sub-ns pulse switching of perpendicularly magnetized free layer via spin-orbit torques for cryogenic memory applications. <i>Applied Physics Letters</i> , <b>2014</b> , 105, 102404	3.4	39
280	Current-driven perpendicular magnetization switching in Ta/CoFeB/[TaOx or MgO/TaOx] films with lateral structural asymmetry. <i>Applied Physics Letters</i> , <b>2014</b> , 105, 102411	3.4	61
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277	Fieldlike and antidamping spin-orbit torques in as-grown and annealed Ta/CoFeB/MgO layers. <i>Physical Review B</i> , <b>2014</b> , 89,	3.3	136
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